

SFD5390
5 AMP

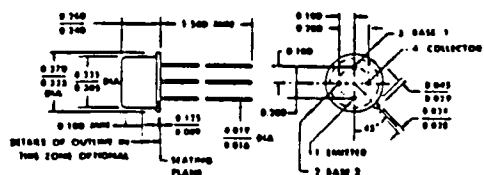


NPN DARLINGTON TRANSISTOR

120 VOLTS

**14830 Valley View Avenue
La Mirada, California 90638
(213) 921-9660
TWX 910-583-4807
FAX 213-921-2396**

CASE STYLE



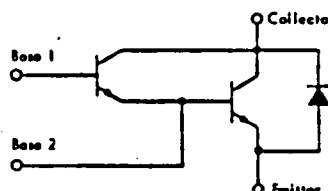
ALL JEDEC TO-33 DIMENSIONS
AND NOTES ARE APPLICABLE.

THE COLLECTOR IS IN ELECTRICAL CONTACT WITH THE CASE.

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FEATURES

- VERY HIGH GAIN 1000 MIN AT 5A
- HIGH SWITCHING SPEED 300ns TYP t_{on}
- LOW $V_{CE(SAT)}$ 1.4V AT 2A
- BUILT IN COMMUTATING DIODE



MAXIMUM RATINGS

RATING	SYMBOL	VALUE	UNIT
Collector Base-1 Voltage	V_{CB-1}	120	Volts
Collector Emitter Voltage	V_{CE0}	80	Volts
Emitter Base-1 Voltage	V_{EB-1}	15	Volts
Continuous Collector Current	I_C	2	Amps
Peak Collector Current	$I_{C(\text{peak})}$	5	Amps
Commutating Diode Current	I_E	2	Amps
Continuous Base-One Current	I_{B1}	0.1	Amps
Continuous Base-Two Current	I_{B2}	1	Amps
Continuous Device Dissipation ($T_c < 100^\circ\text{C}$)	P_D	15	Watts
Continuous Device Dissipation ($T_a \leq 25^\circ\text{C}$)	P_D	1	Watts
Operating Collector Junction Temp. Range	T_j	-65 to 200	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to 200	$^\circ\text{C}$

THERMAL CHARACTERISTICS

CHARACTERISTICS	SYMBOL	VALUE	UNIT
Thermal Resistance Junction to Case	R _{θJC}	6.67	°C/W
Thermal Resistance Junction to Ambient	R _{θJA}	175	°C/W



SOLID STATE DEVICES, INC.

ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	MIN	MAX	UNIT
*Collector-Emitter Breakdown Voltage $I_C = 30\text{mA}$, $I_{B1}=I_{B2}=0\text{Vdc}$	BV_{CEO}	80		Volts
Collector Cutoff Current $V_{CE} = 120\text{Vdc}$, $V_{B1-E} = V_{B2-E}=0\text{Vdc}$ $V_{CE} = 80\text{Vdc}$, $V_{B1-E} = V_{B2-E}=0\text{Vdc}$	I_{CES}		10 1	μA mA
Emitter Cutoff Current $V_{EB1} = 15\text{Vdc}$, $I_C = 0\text{A}$	I_{EB10}		10	μA
DC Current Gain $I_C = 1\text{A}$, $V_{CE} = 5\text{Vdc}$ $I_C = 2\text{A}$, $V_{CE} = 5\text{Vdc}$ $I_C = 5\text{A}$, $V_{CE} = 5\text{Vdc}$	h_{FE}	1000 2000 1000	20000	
*Collector-Emitter Saturation Voltage $I_C = 2\text{A}$, $I_{B1} = 2\text{mA}$ $I_C = 5\text{A}$, $I_{B1} = 10\text{mA}$	$V_{CE(sat)}$		1.4 3.5	Volts
*Base-One Emitter Voltage $I_C = 1\text{A}$, $V_{CE} = 5\text{Vdc}$ $I_C = 2\text{A}$, $V_{CE} = 5\text{Vdc}$	$V_{B1E(ON)}$		1.8 2.2	Volts
Small-Signal Common-Emitter Forward Current Transfer Ratio $I_C = 1\text{A}$, $V_{CE} = 10\text{Vdc}$, $I_{B2} = 0\text{A}$, $f = 20\text{MHz}$	h_{fe}	2		
Common-Base-One Open Circuit Output Capacitance $V_{CB1} = 10\text{Vdc}$, $I_E = 0$	C_{ob10}		150	pF
Turn On Time $I_C=2\text{A}$, $I_{B1(1)}=4\text{mA}$, $I_{B1(2)}=8\text{mA}$, $V_{B1-E}=10\text{Vdc}$, $R_L=14$	t_{on}	300 TYP		ns
Turn Off Time	t_{off}	1.5 TYP		us

*Pulse Test: Pulse Width=300us, Duty Cycle=2%

